

FEATURES

- * 0.56 inch (14.22mm) DIGIT HEIGHT**
- * CONTINUOUS UNIFORM SEGMENTS**
- * LOW POWER REQUIREMENT**
- * EXCELLENT CHARACTERS APPEARANCE**
- * HIGH BRIGHTNESS & HIGH CONTRAST**
- * WIDE VIEWING ANGLE**
- * SOLID STATE RELIABILITY**
- * CATEGORIZED FOR LUMINOUS INTENSITY**
- * LEAD-FREE PACKAGE (ACCORDING TO ROHS)**

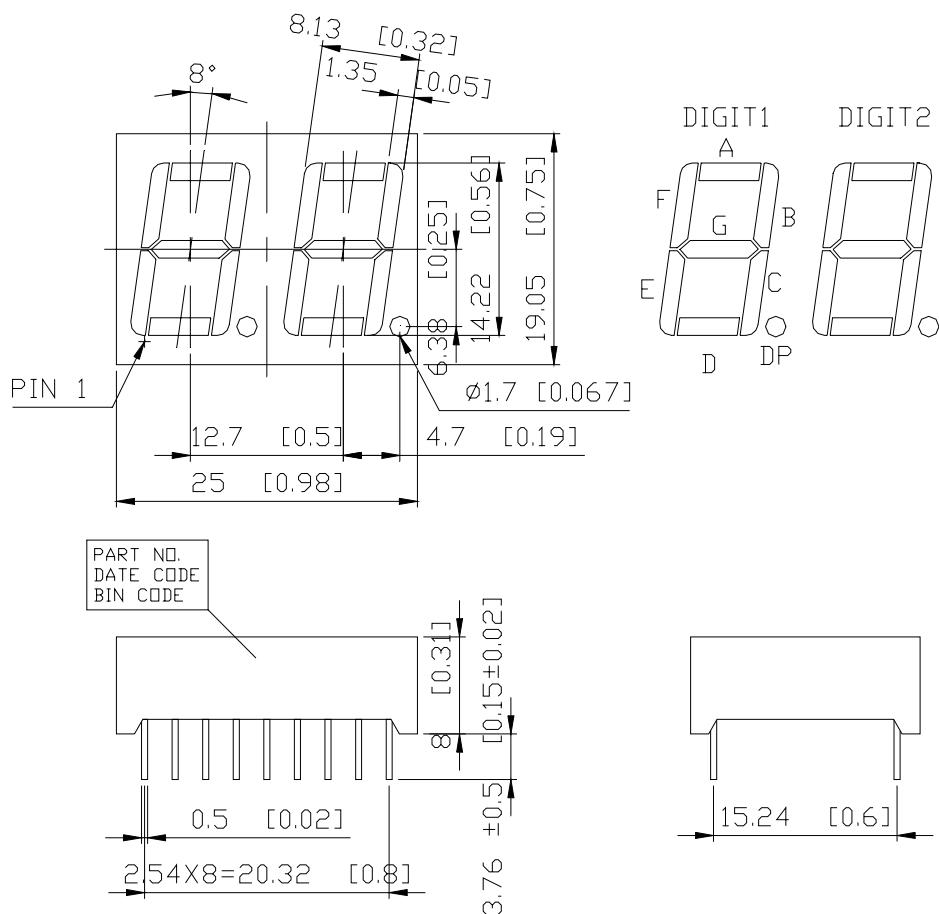
DESCRIPTION

The LTD-6410G is a 0.56 inch (14.22mm) digit height dual digit seven-segment display. The device uses green LED chips(GaP epi on GaP substrate). The display has gray face and white segments.

DEVICE

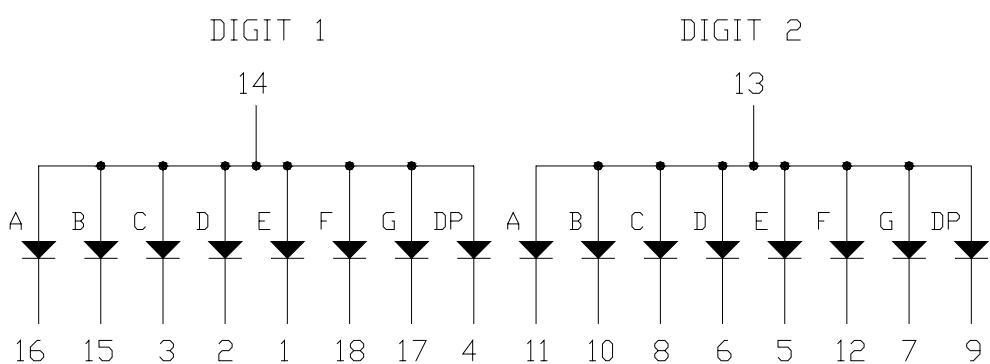
PART NO.	DESCRIPTION
GREEN	COMMON ANODE
LTD-6410G	RT. HAND DECIMAL

PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



PIN CONNECTION

No.	CONNECTION
1	CATHODE E (DIGIT 1)
2	CATHODE D (DIGIT 1)
3	CATHODE C (DIGIT 1)
4	CATHODE DP (DIGIT 1)
5	CATHODE E (DIGIT 2)
6	CATHODE D (DIGIT 2)
7	CATHODE G (DIGIT 2)
8	CATHODE C (DIGIT 2)
9	CATHODE DP (DIGIT 2)
10	CATHODE B (DIGIT 2)
11	CATHODE A (DIGIT 2)
12	CATHODE F (DIGIT 2)
13	COMMON ANODE (DIGIT 2)
14	COMMON ANODE (DIGIT 1)
15	CATHODE B (DIGIT 1)
16	CATHODE A (DIGIT 1)
17	CATHODE G (DIGIT 1)
18	CATHODE F (DIGIT 1)

ABSOLUTE MAXIMUM RATING

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Chip	75	mW
Peak Forward Current Per Chip (Frequency 1Khz, 10% duty cycle)	100*	mA
Continuous Forward Current Per Chip	25	mA
Forward Current Derating from 25°C	0.33	mA/
Reverse Voltage Per Chip	5	V
Operating Temperature Range	-35 to +85	
Storage Temperature Range	-35 to +85	
Soldering Conditions : 1/16 inch below seating plane for 3 seconds at 260°C		

* see figure 5 to establish pulsed condition

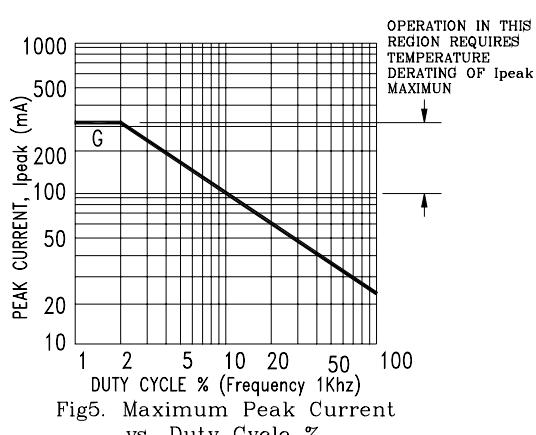
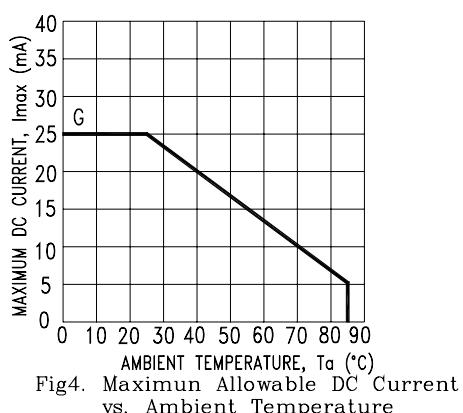
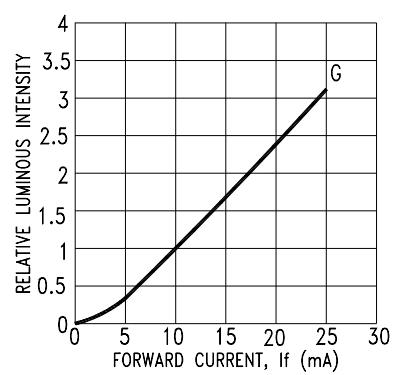
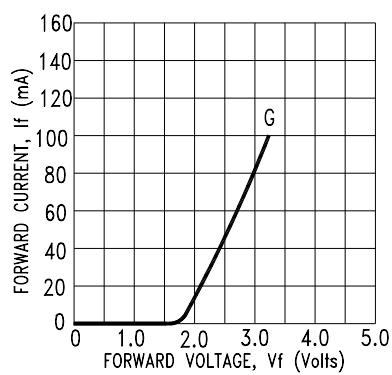
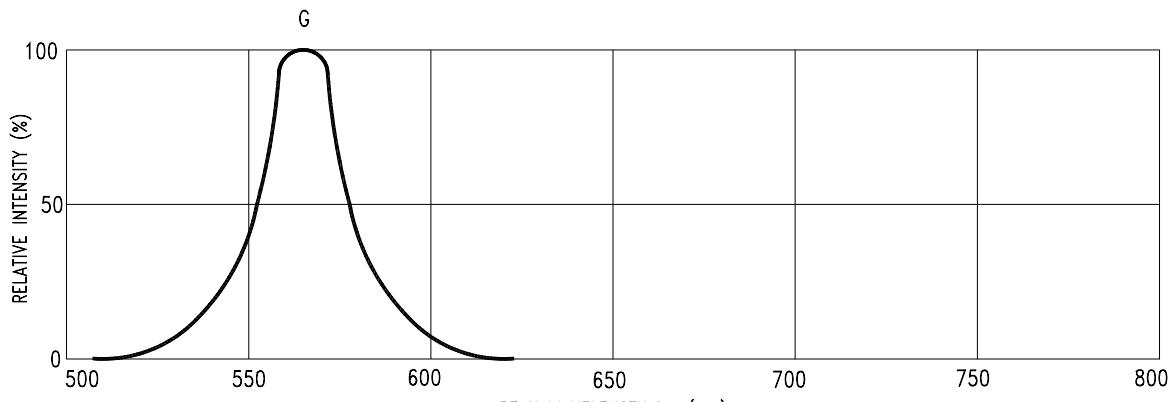
TRICAL / OPTICAL CHARACTERISTICS AT T_A=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I _V	870	2400		μcd	I _F =10mA
Peak Emission Wavelength	λ _p		565		nm	I _F =20mA
Spectral Line Half-Width	Δλ		30		nm	I _F =20mA
Dominant Wavelength	λ _d		569		nm	I _F =20mA
Forward Voltage Per Chip	V _F		2.1	2.6	V	I _F =20mA
Reverse Current Per Chip	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio (Similar Light Area)	I _V -m			2:1		I _F =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)



NOTE: G=GREEN.